Standard Performance Schottky Generic PROM Family 53/63XX-1

Features/Benefits

- Standard Schottky processing
- Reliability proven nichrome fusible links (qualified for MIL-M-38510)
- Drop in compatible ROMs
- PNP inputs for low input current
- Compatible pin configurations for upward expansion
- 4-bit-wide and 8-bit-wide for byte oriented applications

Application

- Microprogram instruction
- Microprocessor program store
- Look up table
- Character generator
- Random logic
- Code converter

Description

The 53/63XX-1-series generic PROM family offers the widest selection of sizes and organizations available in the industry. The 4-bit-wide PROMs range from 256x4 to 1024x4 and feature upward/downward pin out compatibility in the space saving 16 and 18 pin packages. The 8-bit-wide PROMs range from 32x8 to 1024x8 in a wide selection of package sizes. All PROMs have the same programming specifications allowing a single generic programmer.

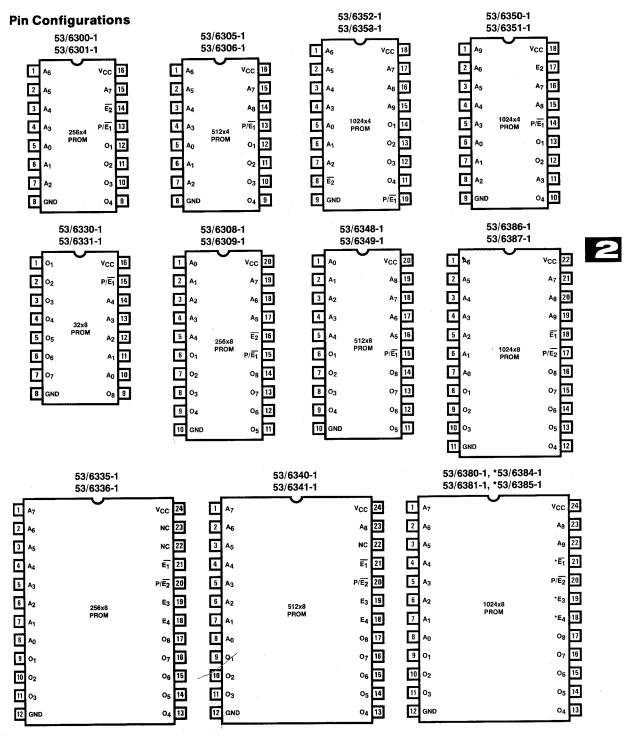
The family features low input current PNP inputs, full Schottky clamping and Three-state and open collector outputs. The nichrome fuses store a logical high and are programmed to the low state. Special on chip circuitry and extra fuses provide preprogramming tests which assure high programming yields and high reliability.

The 63 series is specified for operation over the commercial temperature and voltage range. The 53 series is specified for the military ranges.

Generic PROM Selection Guide

	MEMORY		PAC	KAGE	DEVI	CE TYPE	INTERCHANGEABLE ROM		
Size	Organiza	ition	Pins	Type*	O°C to +75°C	−55°C to +125°C	0°C to +75°C	-55°C to +125°C	
1K	256x4	ОС	16	J, N, F	6300-1	5300-1	6200-1	5200-1	
	20014	TS	10	0, 14, 1	6301-1	5301-1	6201-1	5201-1	
2K	512x4	oc	16	J, N, F	6305-1	5305-1	6205-1	5205-1	
211	31214	TS	10	J, 14, F	6306-1	5306-1	6206-1	5206-1	
		OC.			6350-1	5350-1	6250-1	5250-1	
4K	1024x4	TS	18	J, N, F	6351-1	5351-1	6251-1	5251-1	
411	102484	oc	10	J, IV, F	6352-1	5352-1	6252-1	5252-1	
		TS			6353-1	5353-1	6253-1	5253-1	
1/4K	32x8	oc	16	J. N. F	6330-1	5330-1	6230-1	5230-1	
741	32X0	TS	10	J, N, F	6331-1	5331-1	6231-1	5231-1	
		ОС	00	1.61	6308-1	5308-1		_	
2K	256x8	TS	20	J, N	6309-1	5309-1	_		
2K	25000	ОС	24	LNE	6335-1	5335-1	6235-1	5235-1	
		TS	24	J, N, F	6336-1	5336-1	6236-1	5236-1	
		OC	24	LNIF	6340-1	5340-1	6240-1	5240-1	
4K	512x8	TS	24	J, N, F	6341-1	5341-1	6241-1	5241-1	
41	31280	oc	20	J, N	6348-1	5348-1			
		TS	20	J, N	6349-1	5349-1	_	_	
		ОС			6380-1	5380-1	6280-1	5280-1	
		TS	24	J, N, F	6381-1	5381-1	6281-1	5281-1	
8K	1004/0	oc	24	J, IN, F	6384-1	5384-1	6284-1	5284-1	
or	1024x8	TS			6385-1	5385-1	6285-1	5285-1	
		oc	22	J	6386-1	5386-1	6286-1	5286-1	
		TS	22	J	6387-1	5387-1	6287-1	5287-1	

^{*}Package Types: N is Plastic DIP, J is Ceramic DIP and F is Flat Pak



^{*}NO CONNECTION Replacement for 2708 EPROM.

NOTE: Pin assignments for ceramic (J package), plastic (N package) and flat pack (F package) are the same.

53/63XX-1

Absolute Maximum Ratings

Supply Voltage, VCC -0.5V to +	7.0V
Input Voltage	5.5V
Input Current ————————————————————————————————————	5 m A
Output Current	0 mA
Storage Temperature Range -65°C to +15	50°C

Recommended Operating Conditions

SYMBOL	PARAMETER			53′ (Military)			63' (Commercial)		
OTHIDOL				NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply Voltage		4.5	5.0	5.5	4.75	5.00	5.25	V
ЮН	High Level Output Current				-2.0			-3.2	mA
lou	Low Level Output Current	'00, '01, '05, '06, '08, '09, '40, '41, '48, '49, '50, '51, '52, '53			12			16	mA
lol	Low Level Output Current	'30, '31, '35, '36, '80, '81 '84, '85, '86, '87			8			12	mA
TA	Operating Free Air Tempera	iture	-55		125	0		75	°C

Electrical Characteristics

Over Recommended Operating Free Air Temperature Range (Unless Otherwise Noted)

SYMBOL		PARAMETER	CON	DITIONS	MIN	TYP	MAX	UNIT
V _{IH}	High Level Input	Voltage			2.0			V
VIL	Low Level Input	Voltage					0.8	٧
VIC	Input Clamp Volt	age	V _{CC} = Min, I _I =	–18mA			-1.5	V
VOL	Low Level Outpu	it Voltage	V _{CC} = Min, I _{OL} =	= Max			0.50	V
Ŋ	Maximum Input Current		I .	4.5V (Program Pin) 5.5V (Other Inputs)		.:	1.0	mA
ΉΗ	High Level Input Current		V _{CC} = Max, V _I =				40	μΑ
ΙĮL	Low Level Input Current		V _{CC} = Max, V _I =				-250	μΑ
CI	Input Capacitano	e	$V_{CC} = 5.0V$ $T_{A} = 25^{\circ}C$	V _I = 2.0V		7		pF
cO	Output Capacitar	nce	f = 1 MHz	V _O = 2.0V		8		pF
		'30, '31				90	125	
		'00, '01, '05, '06	V _{CC} = Max			95	130	
lcc	Supply Current	'08, '09,'48, '49				115	155	
.00	35, '36, '40, '41		All inputs grounded			125	170	mA
		'50, '51, '52, '53	All outputs open			130	175	
		'80, '81, '84, '85, '86, '87				135	180	

OPEN COLLECTOR OUTPUT CURRENT

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I look I Outout Lastinas Comment	1 1 4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
ICEX Output Leakage Current	$V_{CC} = Max$, $V_{CC} = 2.4V$	100 4
OLX Table again ago out our	1 VCC Wax, VC - 2.4V	1 100 1 μΑ 1

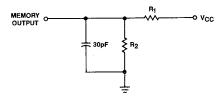
THREE STATE OUTPUT ONLY

Voн	High Level Output Voltage	V _{CC} = Min, I _{OH} = Max	2.4		V
lHZ	High Level OFF State Output Current	$V_{CC} = Max, V_O = 2.4V$		100	μΑ
l _L Z	Low Level OFF State Output Current	$V_{CC} = Max, V_O = 0.5V$		-100	μΑ
los	Output Short Circuit Current	$V_{CC} = 5.0V, V_{O} = 0V$	-20	90	mA

Switching Characteristics
Over Recommended Ranges of TA and VCC (Unless Otherwise Noted)

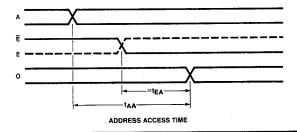
DEVICE TYPE	CONDITIONS (See standard test load)		t _{AA} (ns) ADDRESS ACCESS TIME	tEA & tER (ns) ENABLE ACCESS & RECOVERY TIME	
	R ₁ (Ω)	$R_{2}\left(\Omega\right)$	MAX	MAX	
6300-1, 6301-1	300	600	55	30	
5300-1, 5301-1	375	750	75	30	
6305-1, 6306-1	300	600	60	30	
5305-1, 5306-1	375	750	75	40	
6308-1, 6309-1	300	600	70	30	
5308-1, 5309-1	375	750	80	40	
6330-1, 6331-1	375	750	50	30	
5330-1, 5331-1	560	1120	60	30	
6335-1, 6336-1	375	750	70	30	
5335-1, 5336-1	560	1120	80	40	
6340-1, 6341-1	300	600	70	30	
5340-1, 5341-1	375	750	80	40	
6348-1, 6349-1	300	600	70	30	
5348-1, 5349-1	375	750	80	40	
6350-1, 6351-1	300	600	60	30	
5350-1, 5351-1	375	750	75	40	
6352-1, 6353-1	300	600	60	30	
5352-1, 5353-1	375	750	75	40	
6380-1, 6381-1	375	750	90	40	
5380-1, 5381-1	560	1120	125	40	
6384-1, 6385-1	375	750	90	40	
5384-1, 5385-1	560	1120	125	40	
6386-1, 6387-1	375	750	90	40	
5386-1, 5387-1	560	1120	125	40	

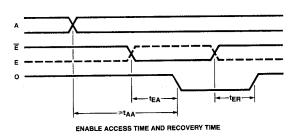
Standard Test Load



Input Pulse Amplitude 3.0V Input Rise and Fall Times 5ns from 1.0V to 2.0V Measurements Made at 1.5V

Definition of Waveforms





Standard Performance Schottky PROM Programming Instructions 53/63XX-1

Device Description

The 53/63XX-1 Generic PROM Family is manufactured with all outputs high in all storage locations. To make an output low at a particular word, a nichrome fusible link must be changed from a low resistance to a high resistance. This procedure is called programming.

Programming Description

To select a particular fusible link for programming, the word address is presented with TTL levels on all inputs a V_{CC} of 5.50V is applied or left applied, and the program pin (ordinarily an enable input) and the output to be programmed are taken to an elevated voltage to supply the required current to program the fuse. The outputs must be programmed one output at a time, since internal decoding circuitry is capable of sinking only one unit of programming current at a time.

Other Enable Inputs

Other enable inputs are logic enables and are not used during programming. They may be high, low or open during programming. When checking that an output is programmed (which is called verification), the PROM must be enabled. The simplest procedure is to tie other enables into the enable position for programming and verification.

Programming Instructions

Timing

The programming procedure involves the use of the program pin (an enable) and the output pin. In order to guarantee that the output transistor is off before increasing the voltage on the output pin, the program pin's voltage pulse must come before the output pin's programming pulse. The programming pulse applied to the output pin and program pin must have a rise time rate of $0.34V/\mu sec$ to $0.46V/\mu sec$.

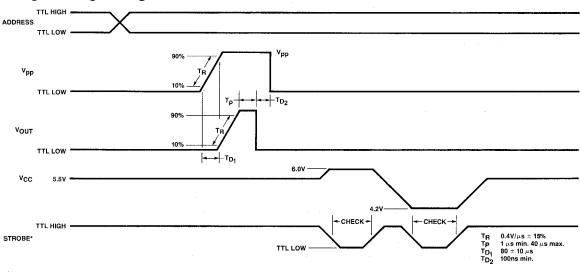
Verification

After programming a device, it can be checked for a low output by enabling the part. Since we must guarantee operation at minimum and maximum V_{CC} , load current and temperature, the device must be required to sink 12mA at 4.2V V_{CC} and 0.2mA at 6.0V V_{CC} at room temperature.

Unprogrammable Units

Visual inspection at 200X prior to encapsulation, test fuses and decoding circuitry tests are used to guarantee a high programming yield of the device in the field. However, because of random defects, it is impossible to guarantee that a link will open without actually programming it. Units returned to MMI as unprogrammable must be accompanied by a complete device truth table clearly indicating the location which could not be programmed, or which was falsely programmed. Otherwise, failure analysis is impossible.

Programming Timing



*Note: Output Load = 0.2mA during 6.0V check.
Output Load = 12mA during 4.2V check.

Programming Parameters

Do not test these parameters or you may program the device.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	LIMITS TYP	MAX	UNIT
tR	Rise Time of Program Pulse Applied Data Out or Program Pin		0.34	0.40	0.46	V/μs
VCCP	VCC Required During Programming		5.40	5.50	5.60	V
I _{OLV} 1	Output Current Required During Verification	Chip Enabled TA = +25°C, VCC = 4.2V	11	12	13	mA
lOLV2	Output Current Required During Verification	Chip Enabled TA = +25°C, VCC = 6.0V	0.10	0.2	0.30	mA
MDC	Maximum Duty Cycle During Automatic Programming of Program Pin and Output Pin	tp/tC			25	%
V _{pp}	Required Programming Voltage on Program Pin		27	27	33	٧
V _{out}	Required Programming Voltage on Output Pin		20	20	26	V
IL	Current Limit of Power Supply Feeding Program Pin and Output During Programming	V _{pp} = 33V, V _{out} = 26V, V _{CC} = 5.50V	240			mA
^t D1	Required Time Delay Between Disabling Memory Output and Application of Output Programming Pulse	Measure at 10% Levels	70	80	90	μs
tD2	Required Time Delay Between Removal of Programming Pulse and Enabling Memory Output	Measure at 10% Levels	100			ns



Programming Speed

Typically, fuses will blow on the rise time of the first pulse. In automated programmers which must copy devices in a short time because of the production requirements, the following pulse and voltage sequences have been found to maximize reliability, programming yield and throughput. The device should be verified after each programming attempt and be advanced to the next bit if the device has programmed.

PULSE NUMBER	PROGRAM PIN VOLTAGE	OUTPUT VOLTAGE
1 to 3	27V	20V
4 to 6	30V	23V
7 to 9	33V	26V

NOTE: The 5330/1 and 6330/1 do not have a program pin. For these devices the output only is used in programming a particular selected bit and the device must be in the disabled state.

Commercial Programmers

MMI PROMs are designed and tested to give a programming yield greater than 95%. Field reports agree with this expectation. Several companies make commercial programmers which will

properly program MMI PROMs. MMI makes it a practice to review these commercial programmers and works closely with the manufacturers to maintain a high programming yield and high reliability of programmed parts. If your programming procedures have a lower yield, then check your programmer. It may not be properly calibrated for the "Dash-One" series of PROMs—53xx-1 and 63xx-1. Calibration must agree with the timing charts supplied in this publication. Monolithic Memories intends a systematic review of commercially available programmers, and will periodically issue a list of approved models.

Programming is final manufacturing—it must be quality-controlled. Equipment must be calibrated as a regular routine, ideally under the actual conditions of use. The best method involves a storage scope, with DC current probes clamped over the external wires to the program pin and the output pin. The current should not be limited at a value less than 240mA. This can be checked by using a 50-ohm resistor as a load. Each time a new board or a new programming module is inserted, the whole system should be checked. Both timing and voltages must meet published specification's for the device.

Remember—The best PROMs available can be made unreliable by improper programming techniques.